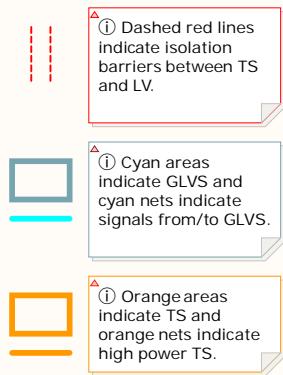


A



**Specifications:**

V<sub>in</sub>, max = 600 VDC  
V<sub>out</sub>, max = 245 VRMS (SVPWM)  
f<sub>sw</sub> = 50 kHz  
P<sub>out</sub>, max = 40kW  
I<sub>out</sub>, max = 80 ARMS

Liquid cooled with water at 50°C max

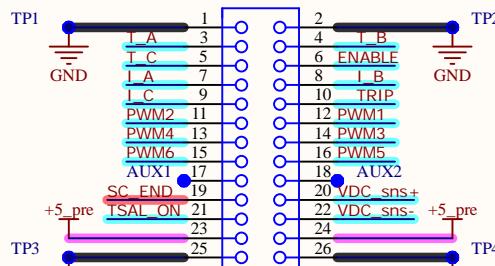
**Changelog:**

Version 1.0:  
- Base version, sent to production 15-02-2024

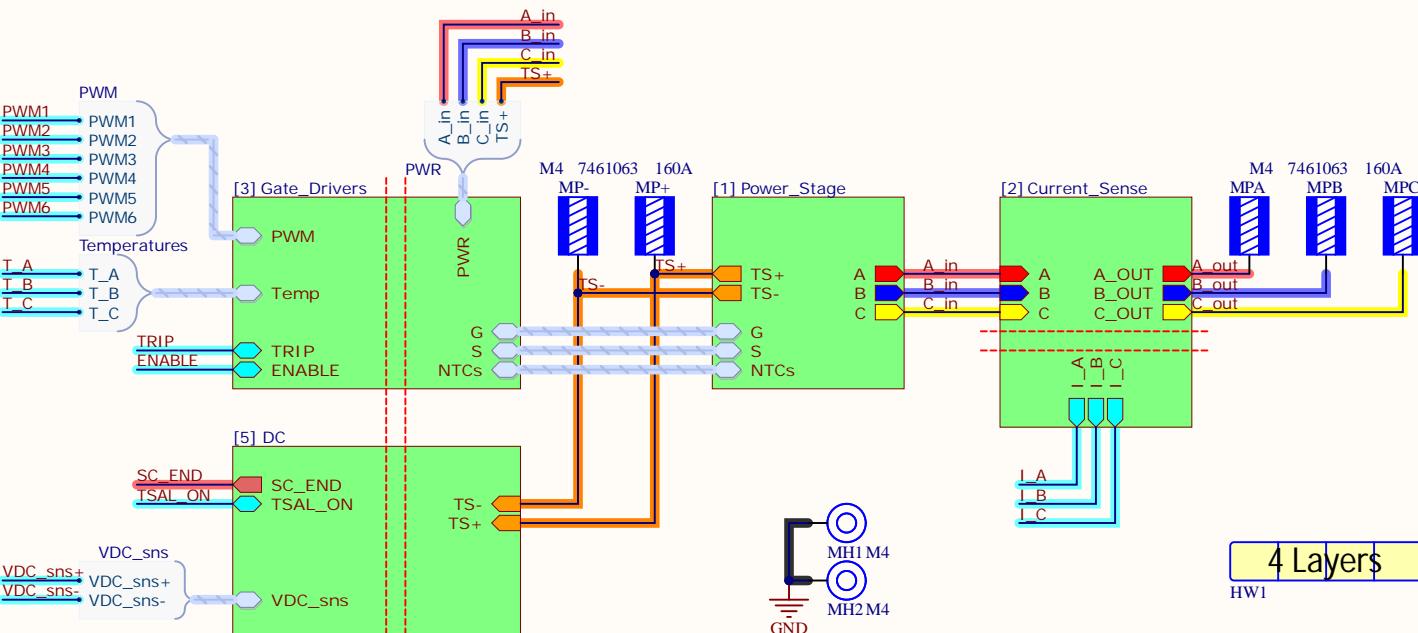
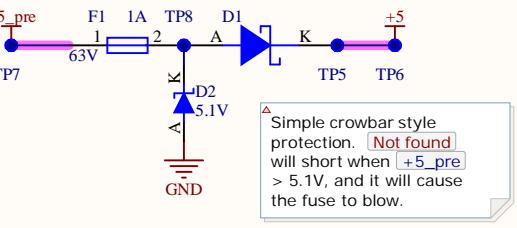
Version 1.1:  
- Added 5V supply protections  
- Swapped pins 4 and 5 in gate drivers' LDOs  
- Swapped MP+ and MP-, and their silkscreen  
- Added testpoints for current sensors' reference  
- Added testpoints for VDC\_sns+ and VDC\_sns-

- Renamed testpoints in [3]  
- Added various silkscreen texts and indications

## LV Connector

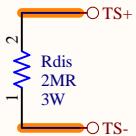


## OCP, OVP, reverse

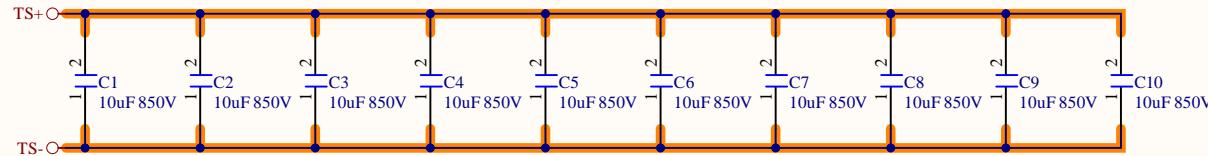


Company:	e-Tech Racing	e-techracing.es	
Project:	Inverter Power	Variant: Leapers	
Size:	Page Contents: Inverter_Power.SchDoc	Version: 1.1	
		Department: Powertrain	
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## Passive discharge



## DC Bus capacitors, 100uF, Murata FHA85Y106KS



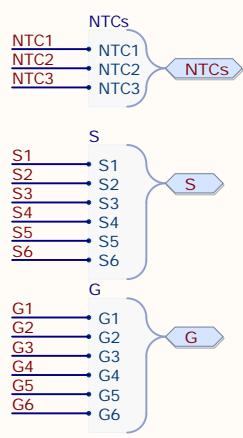
### DC Link design considerations:

$V_C > 1.1 \cdot V_{max} = 1.1 \cdot 600 V = 660 V \rightarrow 850 V$

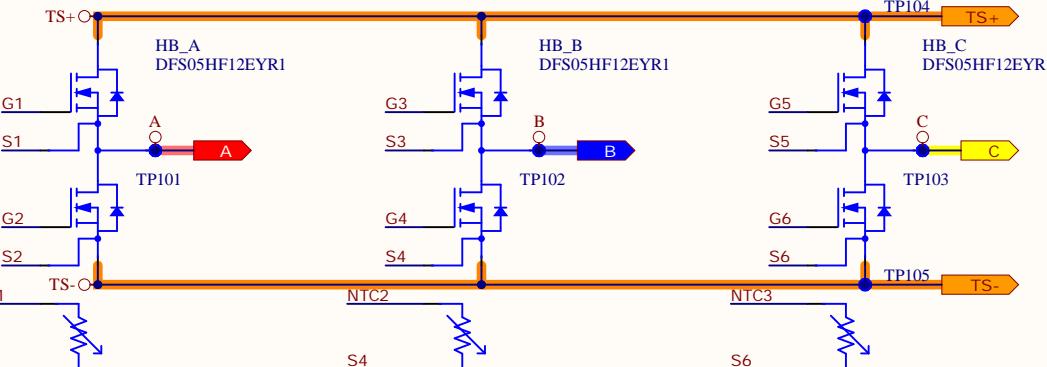
$I_{C,RMS} \approx 0.65 \cdot I_{phase,RMS} = 0.65 \cdot 80 A, RMS = 52 A, RMS \rightarrow 10 \times 5 A, RMS (\Delta T = 10 ^\circ C)$   
 $C > I_{C,RMS} / (V_{ripple} \cdot f_{sw}) = 52 A, RMS / (15V \cdot 50 kHz) \approx 79 \mu F \rightarrow 10 \times 10 \mu F$

Lowering the switching frequency will proportionally lower the current rating for the same voltage ripple or proportionally increase the voltage ripple for the same output current. Check:  
<https://www.specterengineering.com/blog/2019/9/7/dc-link-capacitor-selection-for-your-inverter>

## INPUTS/OUTPUTS



## SiC Half-Bridges



### Semiconductor details:

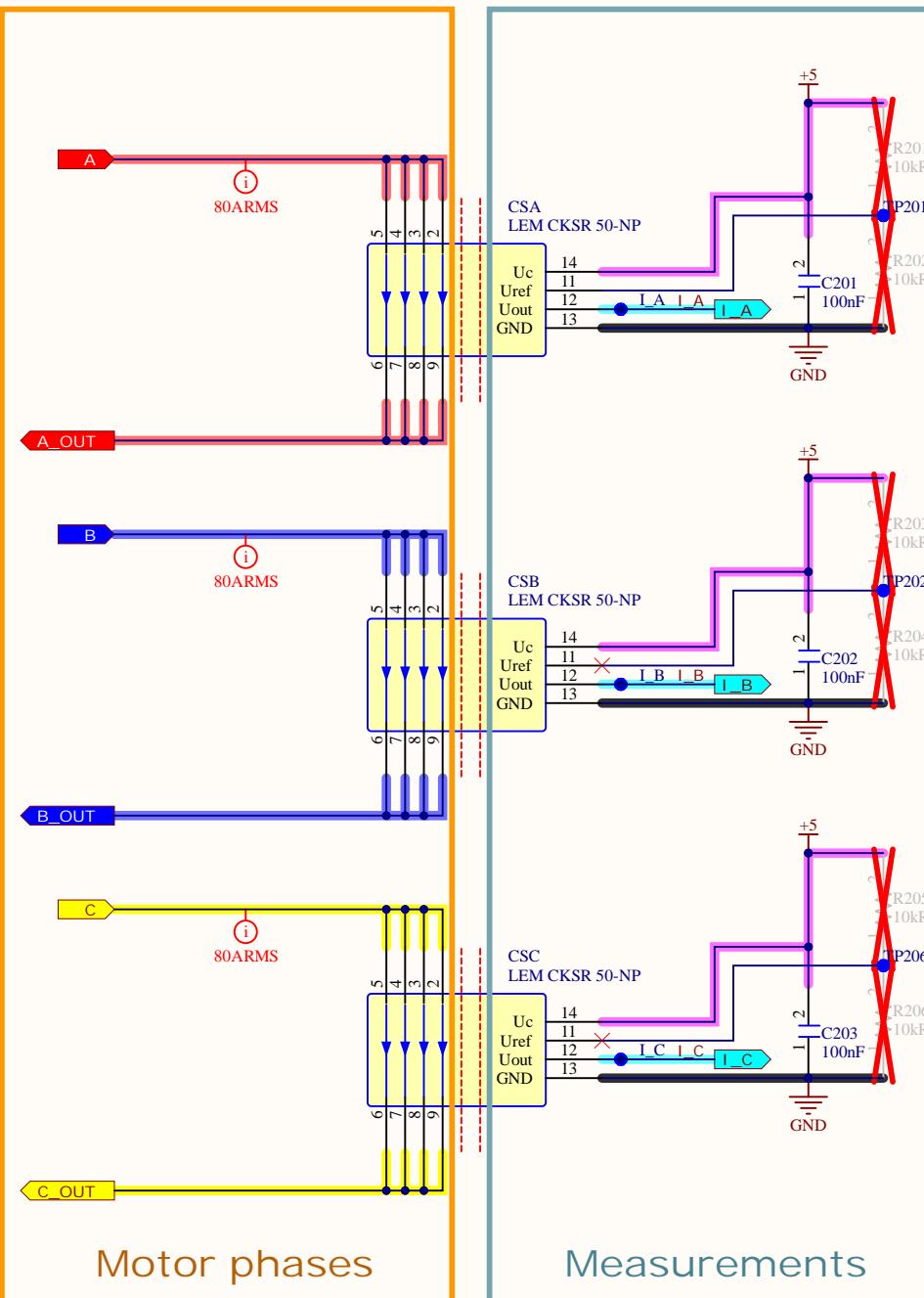
$V_{DSS}(\text{breakdown}) = 1200 V // 1200 V$   
 $R_{on} = 5.5 .. 13 m\Omega // 16.0 .. 28.8 m\Omega$   
 $V_{f,D} = 3.3 .. 4 V // 4.9 .. 5.5 V$   
 $T_{rr} = 41.5 .. 45 ns // 20.0 ns$   
 $Q_{rr} = 2.19 .. 3.94 \mu C // 1.30 \mu C$   
 $R_{th,Jc} = 0.12 .. 0.15 K/W // 0.543 K/W$   
 $Q_G = 520 nC // 236 nC$   
 $C_{in} = 14.5 nF // 6.6 nF$   
 $R_G(\text{int}) = 1.9 \Omega // 2.4 \Omega$   
 $V_{GS(th)} = 2.8 .. 4.8 V // 1.8 .. 3.6 V$

Company:	e-Tech Racing	e-techracing.es	
Project:	Inverter Power	Variant: Leapers	
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A

CSA , CSB , CSC

CKSR 50-NP/SP1 configured with Number of primary turns = 1 (R\_phase-connector = 0.18 mΩ)



B

CSA , CSB , CSC

CKSR 50-NP/SP1 2.5V internal reference is used in order to have equal measuring range for positive and negative values. Voltage divider implemented just in case.

I\_A , I\_B , I\_C

$$U_{\text{meas}} = (12.5 \text{mV/A} \cdot I_{\text{meas}} + U_{\text{ref}})$$

For ±150Apk:  
V<sub>meas\_pk+</sub> = 4.375V  
V<sub>meas\_pk-</sub> = 0.625V

C201 , C202 , C203

The fluxgate oscillator draws current pulses of up to 30 mA at a rate of ca. 900 kHz. In the case of a power supply with high impedance, it is advised to provide local decoupling (100 nF or more, located close to the transducer).

C

CSA , CSB , CSC

AC insulation test  
RMS voltage, 50 Hz,  
1 min:

$$U_d = 4.3 \text{kV} > 3 \cdot V_{\text{max}} = 1.8 \text{kV}$$

D

Company:	e-Tech Racing	e-techracing.es	
Project:	Inverter Power	Variant: Leapers	
Size:	Page Contents: [2]Current_Sense.SchDoc	Version: 1.1	
		Department: Powertrain	
Author:	David Redondo	dredondovinolo@gmail.com	Sheet 3 of 5
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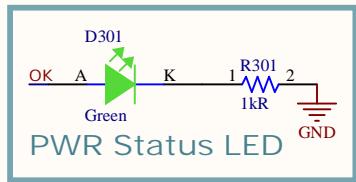
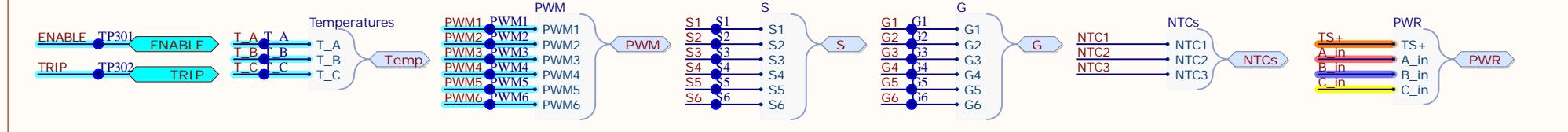
1

2

3

4

## INPUTS/OUTPUTS



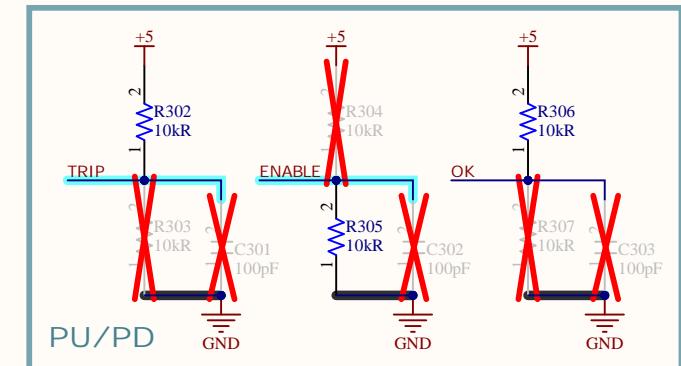
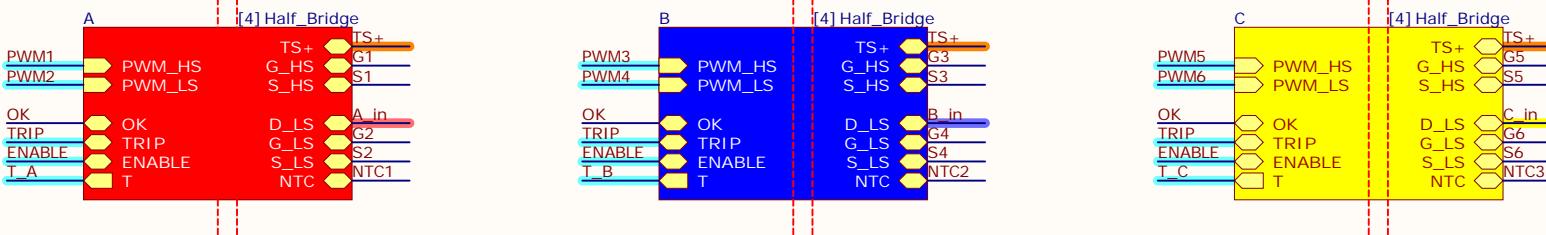
**[T\_A, T\_B, T\_C]**  
Look-up table obtained with MATLAB script which can be found in the simulations folder.  
For different temperatures:  
 $V_{meas}(0^\circ\text{C}) = 0.246\text{V}$   
 $V_{meas}(25^\circ\text{C}) = 2\text{V}$   
 $V_{meas}(50^\circ\text{C}) = 2.578\text{V}$   
 $V_{meas}(90^\circ\text{C}) = 2.864\text{V}$

B

B

C

C



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Project:	Inverter Power	Variant: Leapers	
Size:	Page Contents: [3]Gate_Drivers.SchDoc	Version: 1.1	
		Department: Powertrain	
Author:	David Redondo	dredondovinolo@gmail.com	Sheet 4 of 5
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1

2

3

4

A

**U\_HS, U\_LS**

- TRIP** and **OK** signals are in open drain configuration, so they can be paralleled.
- IN- is not used and tied to **GND**.
- ENABLE** to be given by MCU in active-high mode. When set to low for more than 1  $\mu$ s, **TRIP** is reset.
- Temperature sensing using low-side drivers. Ain outputs a current of 200  $\mu$ A. PWM to analog using a RC filter, to be fed directly to MCU ADC. **R405**, **R406** and **C411** from SPICE simulation.
- Miller clamp protection is used.
- RGS\_HS**, **RGS\_LS**: External gate pull-down is implemented even though the gate drivers implement an active pull-down.
- Overcurrent detection is not implemented.

**LDO\_HS, LDO\_LS**

An LDO is implemented to trim **VEE\_HS\_A** and **VEE\_LS\_A** during testing to fine tune the necessary negative gate voltage. Feedback voltage divider adjusted with a Python script which can be found in the simulations folder.

$$\text{VEE} = -1.186 \cdot (1 + R1/R2)$$

$$R1 + R2 \approx 100 \text{ k}\Omega$$

Leapers  $\rightarrow R1 = 36 \text{ k}\Omega$ ,  $R2 = 56 \text{ k}\Omega$

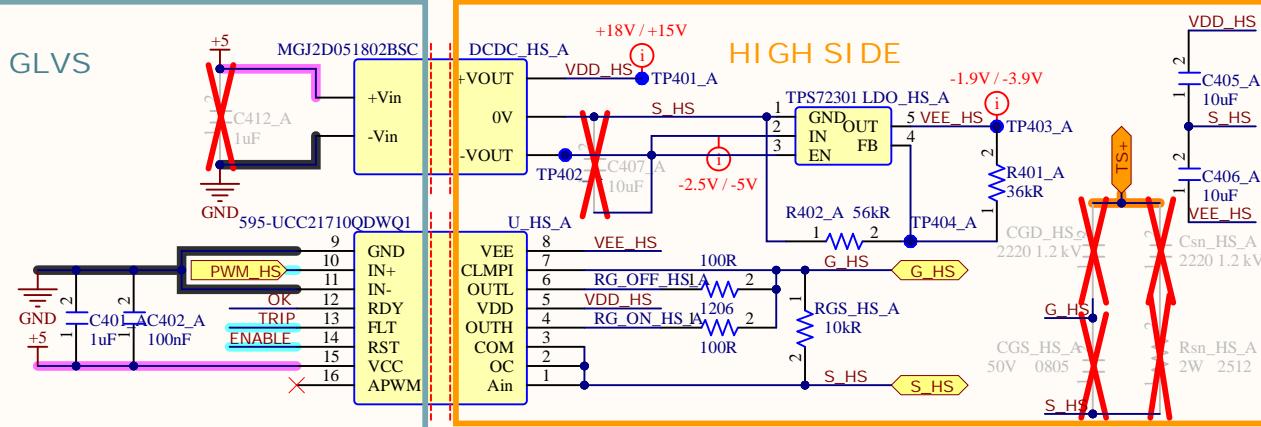
Wolfspeed  $\rightarrow R1 = 68 \text{ k}\Omega$ ,  $R2 = 30 \text{ k}\Omega$

**DCDC\_HS, DCDC\_LS**

Isolation test voltage (Qualification tested for 1 minute): 5200 VDC

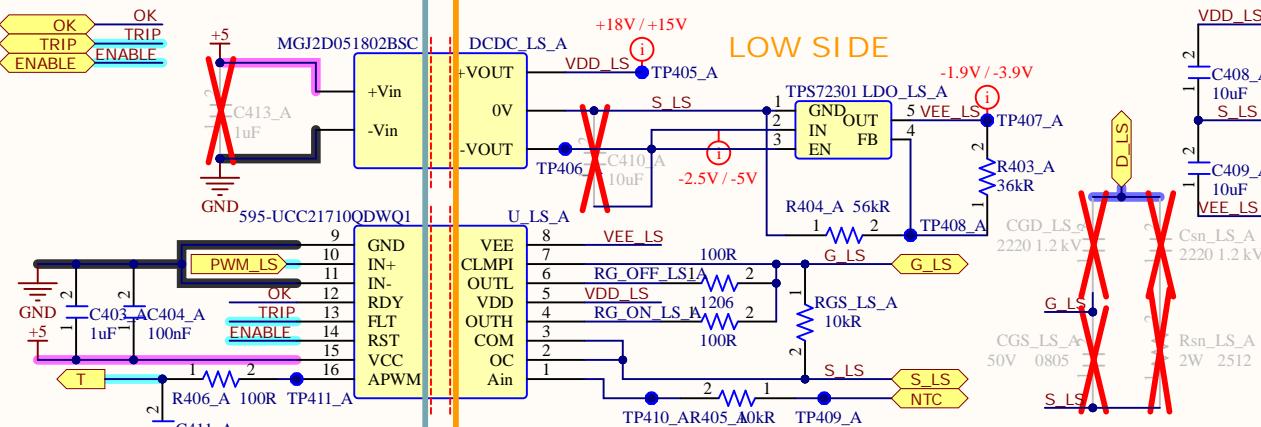
**U\_HS, U\_LS**

VIOTM ( $t = 60$  s (qualification test)): 8000 VPK

**GLVS****V\_GS values:**

The values can be modified by replacing **DCDC\_HS** and **DCDC\_LS** with one from the following list: MGJ2D051505SC, MGJ2D051509SC, MGJ2D051515SC, MGJ2D051802SC, MGJ2D052003SC, MGJ2D052005SC. LDO voltages must also be adjusted.

Minimum gate driver current and power:  
 $I_{GD(\min)} = f_{sw} \cdot O_G = 50 \text{ kHz} \cdot 520 \text{ nC} = 26 \text{ mA}$   
 $P_{\min} = \Delta V_{GS} \cdot I_{GD(\min)} = 20 \text{ V} \cdot 26 \text{ mA} = 0.52 \text{ W} \rightarrow 2 \text{ W}$

**OK, TRIP, ENABLE****RG\_ON\_HS, RG\_OFF\_HS, RG\_ON\_LS, RG\_OFF\_LS**

Essentially, a lower value for the gate resistors will reduce switching losses as the MOSFETs will switch faster and thus spend less time switching. Switching faster also means that the  $dV/dt$  will be higher, which can be responsible of EMI increase. The considered values of 3.3  $\Omega$  are recommended by the datasheet.

**CGS\_HS**, **CGS\_LS**, **CGD\_HS**, **CGD\_LS**, **Csn\_HS**, **Csn\_LS**, **Rsn\_HS**, **Rsn\_LS**

DNP, but they could be useful with EMI related issues to decrease  $dV/dt$ . Implementing them could result in further issues with the power limit for **DCDC\_HS** and **DCDC\_LS**, as the gate charge would increase significantly. The maximum allowed capacitance would be:

$$CGS_{\max} = 2 \cdot P_{DCDC} / (\Delta V_{GS}^2 \cdot f_{sw}) = 2 \cdot 2 \text{ W} / ((20 \text{ V})^2 \cdot 50 \text{ kHz}) = 200 \text{ nF}$$

Company: e-Tech Racing e-techracing.es



Project: Inverter Power Variant: Leapers

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Author: David Redondo dredondovinolo@gmail.com Sheet 5 of 5

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A

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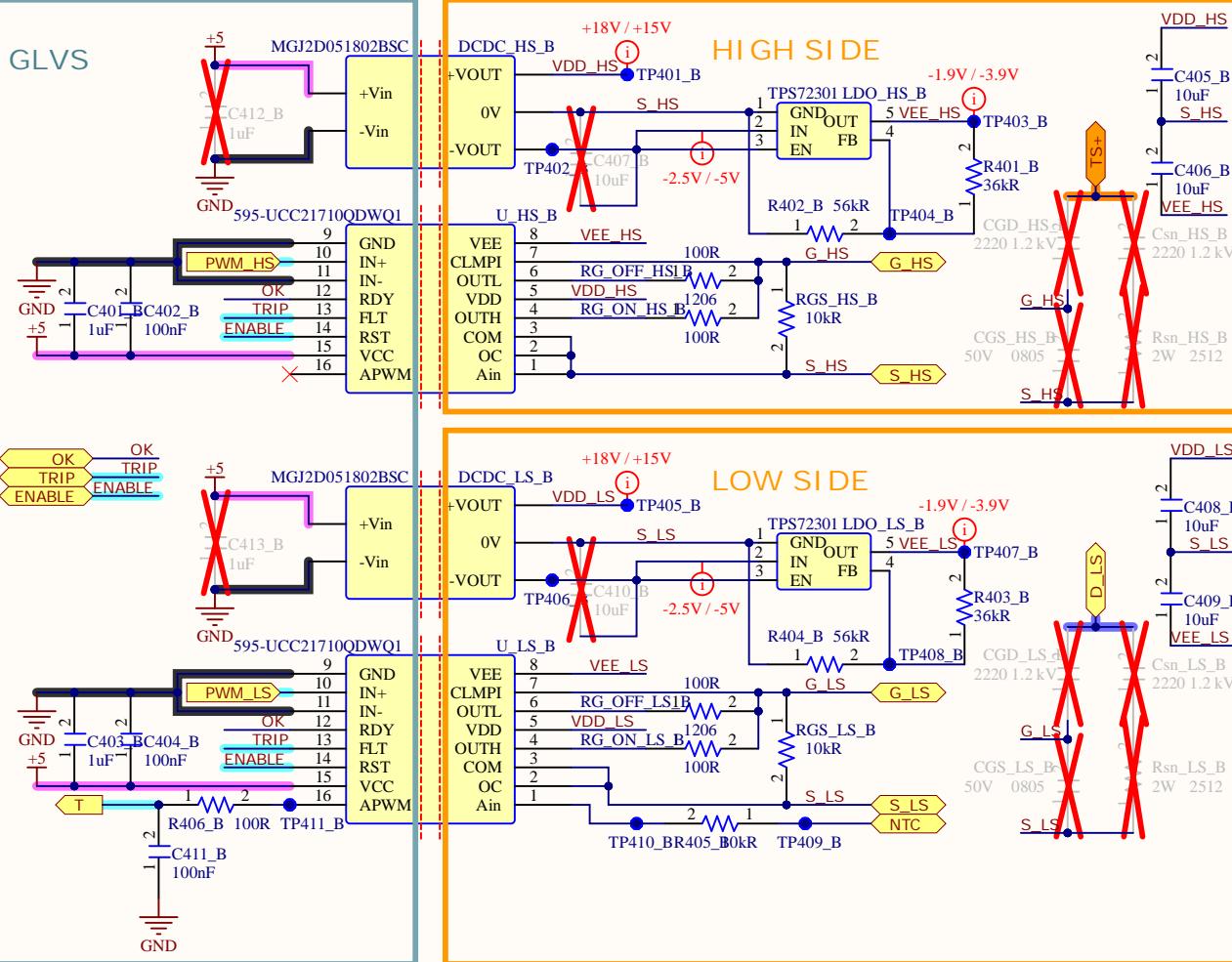
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**RG\_ON\_HS, RG\_OFF\_HS, RG\_ON\_LS, RG\_OFF\_LS**

Essentially, a lower value for the gate resistors will reduce switching losses as the MOSFETs will switch faster and thus spend less time switching. Switching faster also means that the  $dV/dt$  will be higher, which can be responsible of EMI increase. The considered values of 3.0  $\Omega$  are recommended by the datasheet.

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DNP, but they could be useful with EMI related issues to decrease  $dV/dt$ . Implementing them could result in further issues with the power limit for **DCDC\_HS** and **DCDC\_LS**, as the gate charge would increase significantly. The maximum allowed capacitance would be:

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A

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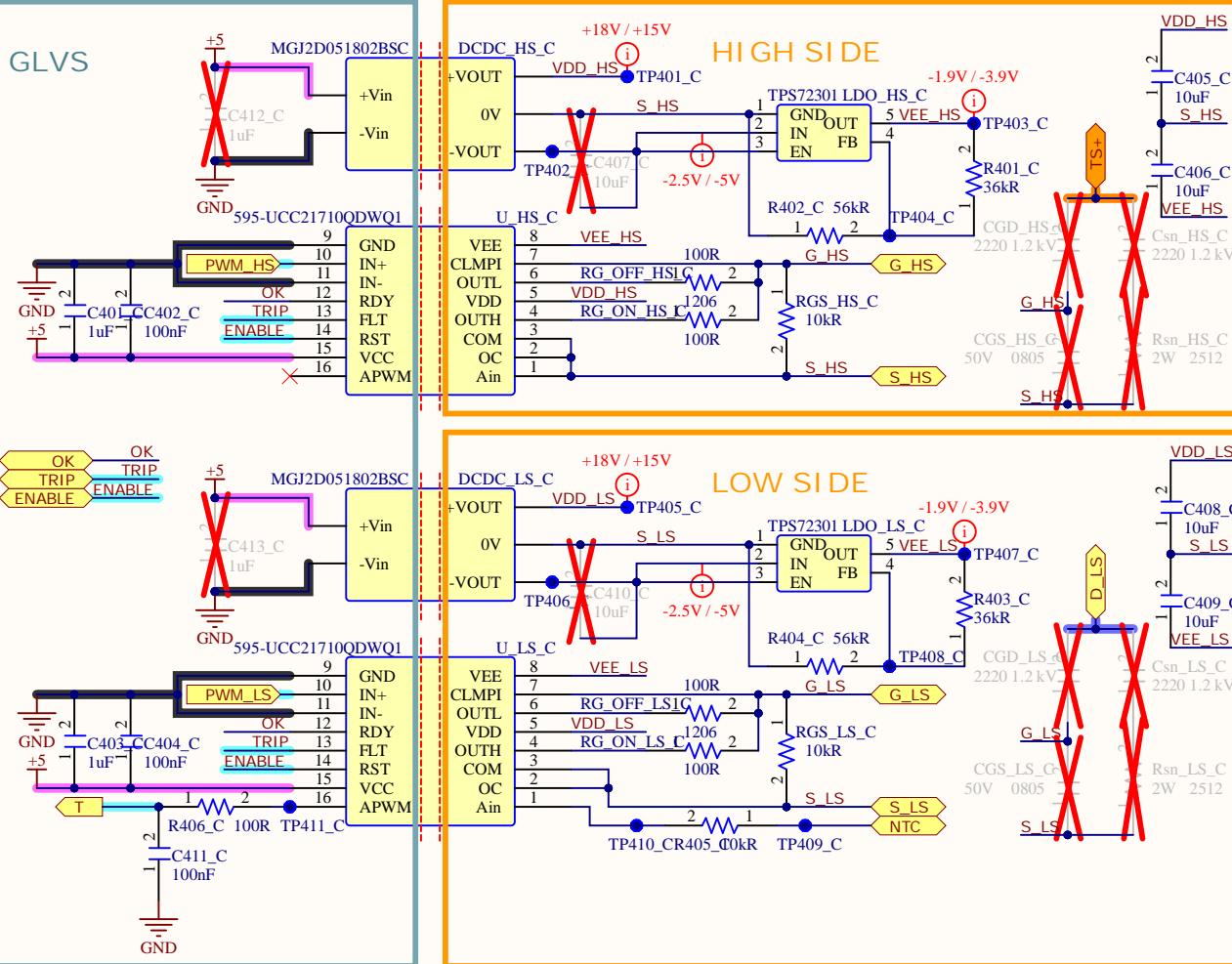
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Isolation test voltage (Qualification tested for 1 minute): 5200 VDC

**U\_HS, U\_LS**

VIOTM ( $t = 60$  s (qualification test)): 8000 VPK

**GLVS****V\_GS values:**

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**RG\_ON\_HS, RG\_OFF\_HS, RG\_ON\_LS, RG\_OFF\_LS**

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**CGS\_HS**, **CGS\_LS**, **CGD\_HS**, **CGD\_LS**, **Csn\_HS**, **Csn\_LS**, **Rsn\_HS**, **Rsn\_LS**

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A

## Discharge resistors:

$$t_{dis} = R_{dis} \cdot C \cdot \ln(V_{initial}/V_{final}) = (470 \text{ k}\Omega / 24) \cdot (100 \mu\text{F}) \cdot \ln(600 \text{ V} / 60 \text{ V}) = 4.509 \text{ s}$$

$$P(R_{dis}, \text{max}) = V_{max}^2 / R_{dis} = 600 \text{ V}^2 / 470 \text{ k}\Omega = 0.766 \text{ W} < 1 \text{ W}$$

$$I_{dis, \text{max}} = 600 \text{ V} / (470 \text{ k}\Omega / 24) = 30.64 \text{ mA}$$

## U503

Single supply configuration as per datasheet.

$$\text{Maximum differential input voltage} = 6.833 \text{ V} - 677 \text{ mV} = 6.156 \text{ V} < 30 \text{ V}$$

$$VDC_{div} = (TS+ - TS-) \cdot 4.7 \text{ k}\Omega / (4.7 \text{ k}\Omega + 6 \cdot 68 \text{ k}\Omega)$$

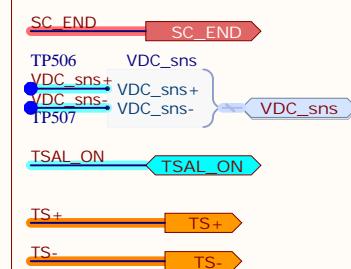
$$600 \text{ V} \cdot 4.7 \text{ k}\Omega / (4.7 \text{ k}\Omega + 6 \cdot 68 \text{ k}\Omega) = 6.833 \text{ V}$$

$$60 \text{ V} \cdot 4.7 \text{ k}\Omega / (4.7 \text{ k}\Omega + 6 \cdot 68 \text{ k}\Omega) = 683 \text{ mV}$$

$$P_{R4} = I_{R4}^2 \cdot R_4 = ((600 \text{ V} / (4.7 \text{ k}\Omega + 6 \cdot 68 \text{ k}\Omega)) / 68 \text{ k}\Omega)^2 \cdot 68 \text{ k}\Omega = 144 \text{ mW} \rightarrow 1206 \text{ package}$$

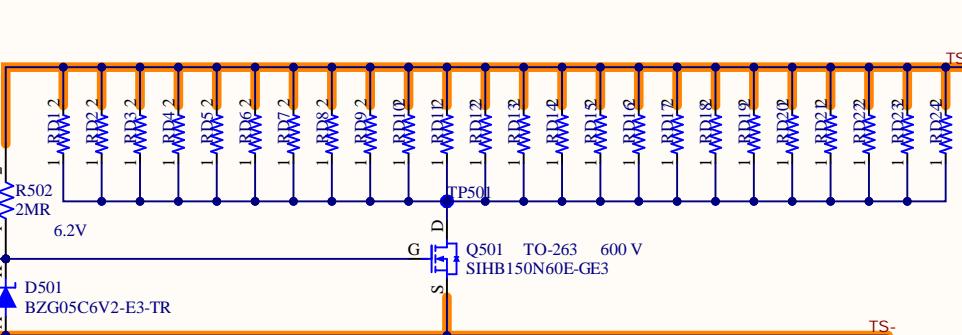
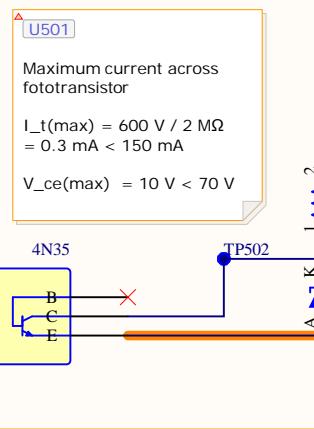
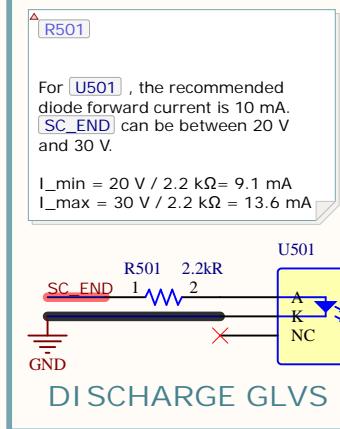
$$V_{TSAL} = 5 \text{ V} \cdot 4.7 \text{ k}\Omega / (4.7 \text{ k}\Omega + 30 \text{ k}\Omega) = 677 \text{ mV} \equiv 59.46 \text{ V in } TS+ - TS-$$

## INPUTS/OUTPUTS

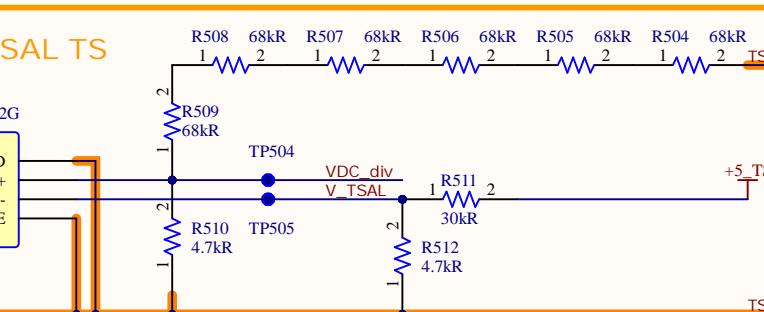
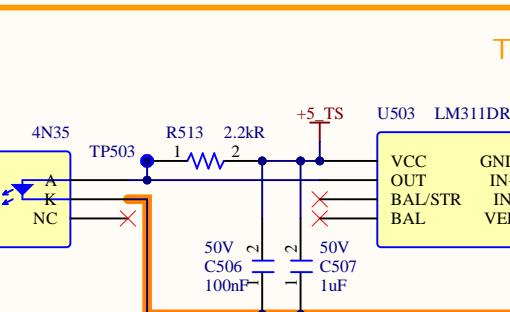
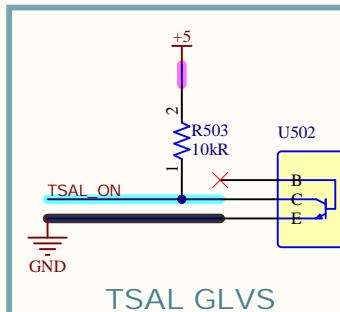


$$(TS+ - TS-) > 60 \text{ V} \rightarrow TSAL\_ON = 0 \text{ V}$$

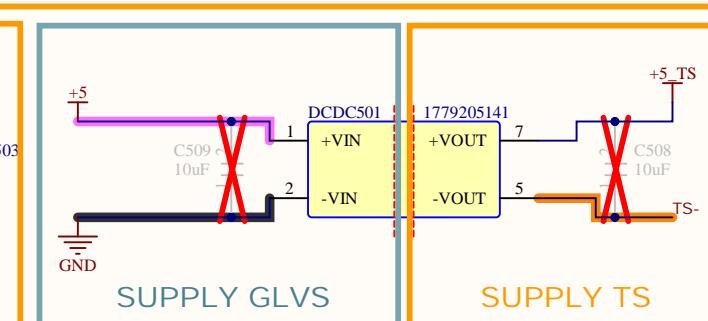
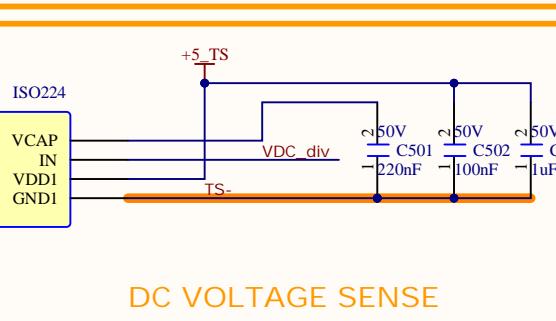
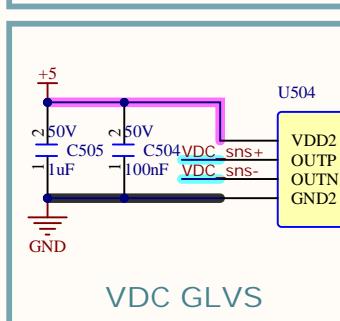
$$(TS+ - TS-) < 60 \text{ V} \rightarrow TSAL\_ON = 5 \text{ V}$$



## DISCHARGE TS

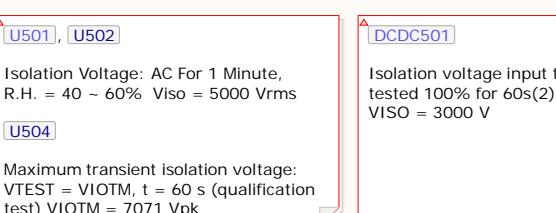
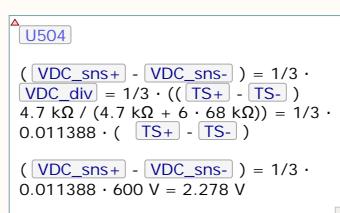


## TSAL TS

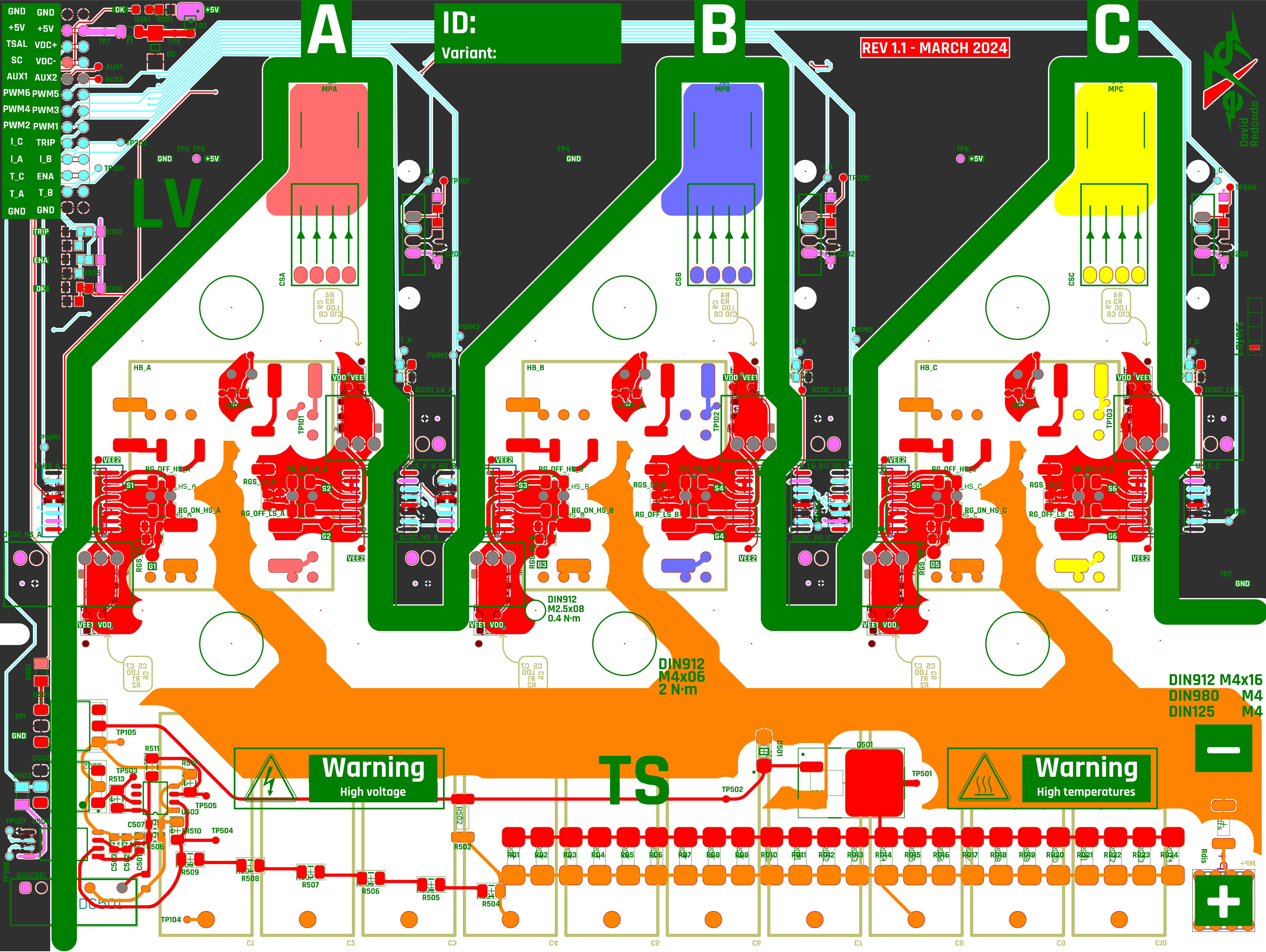


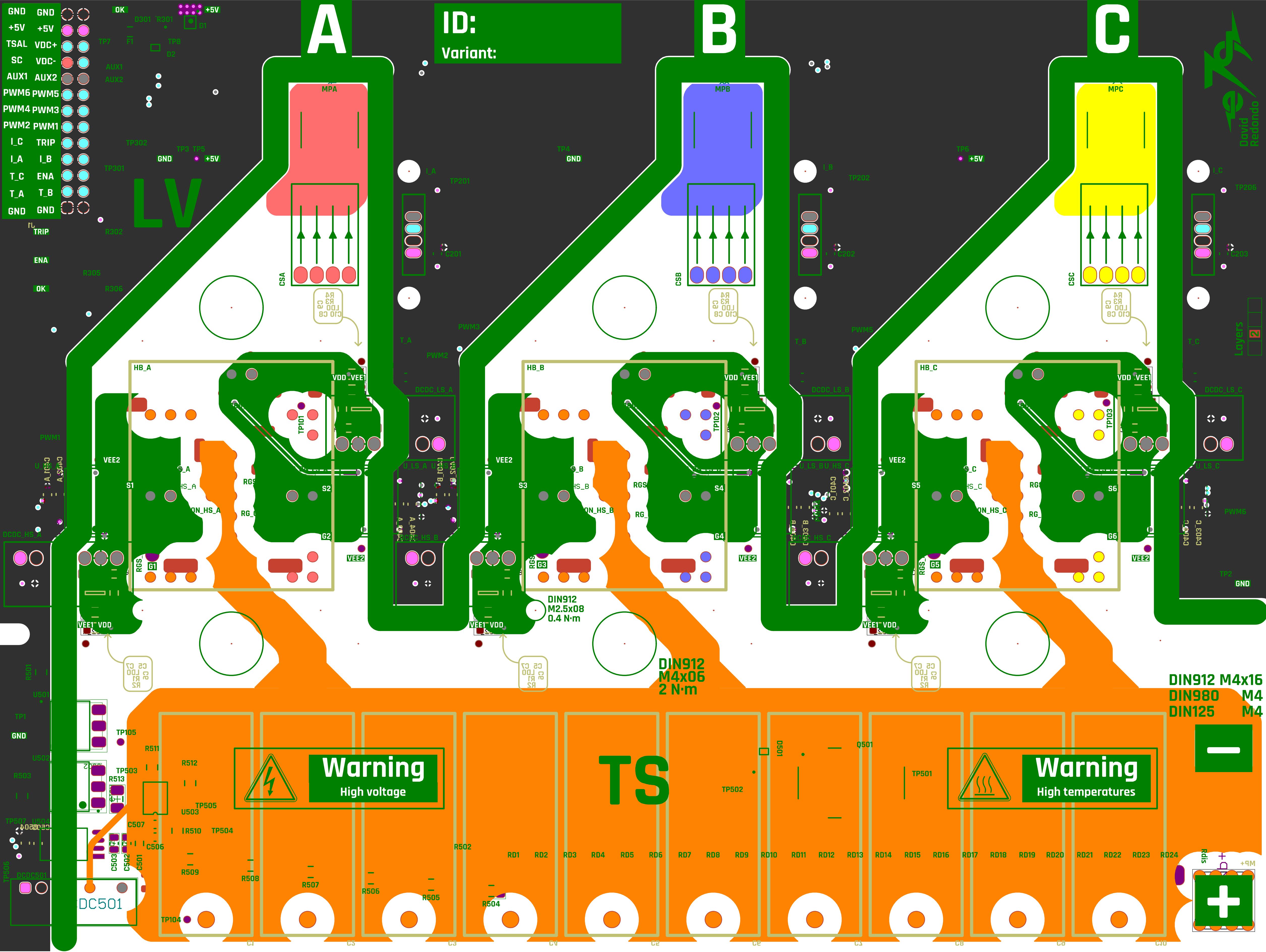
## SUPPLY GLVS

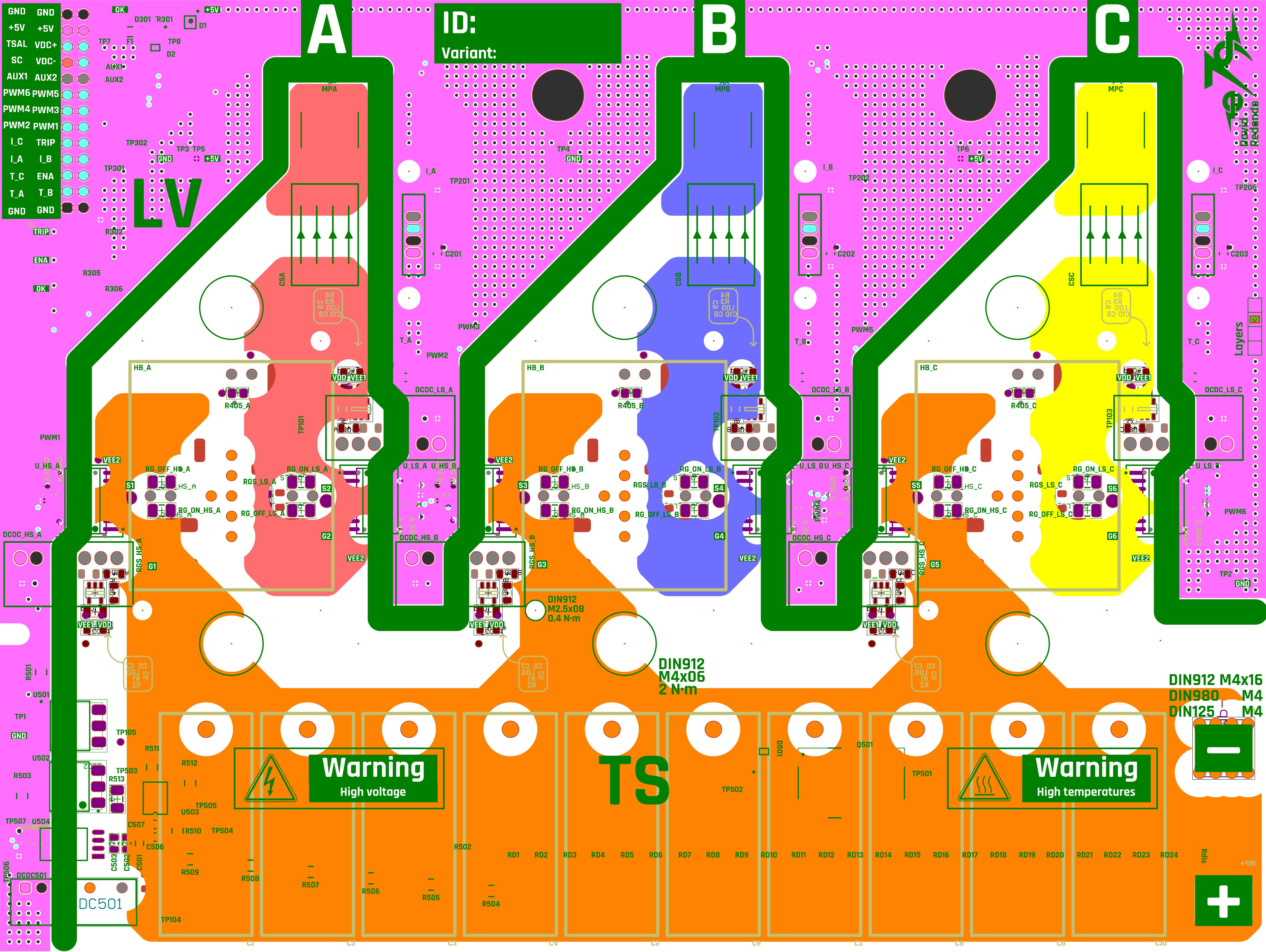
## SUPPLY TS

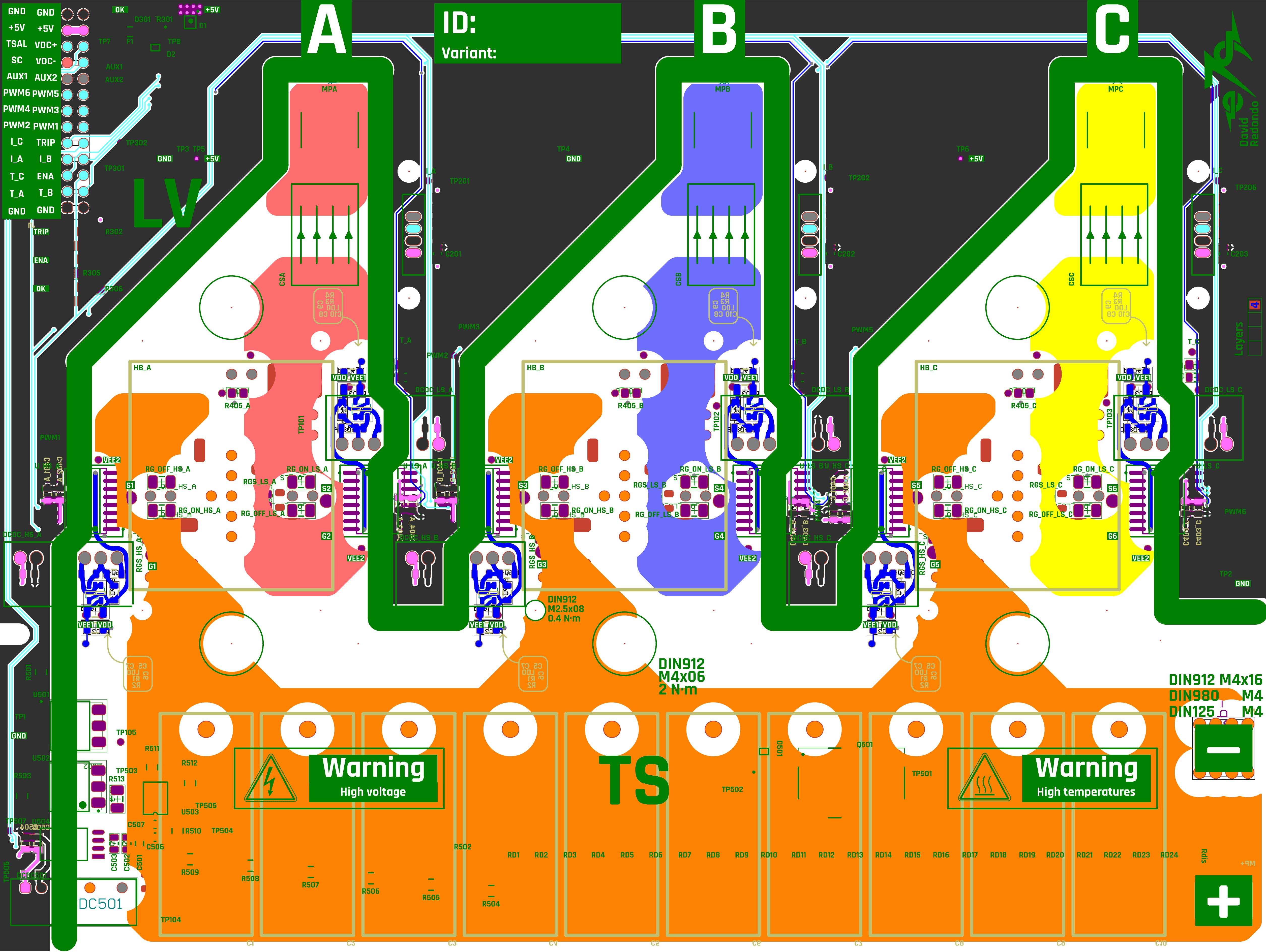


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Department: Powertrain		
Author: David Redondo	dredondovinolo@gmail.com	Sheet * of *
Checked by: _		Date: 20/03/2024

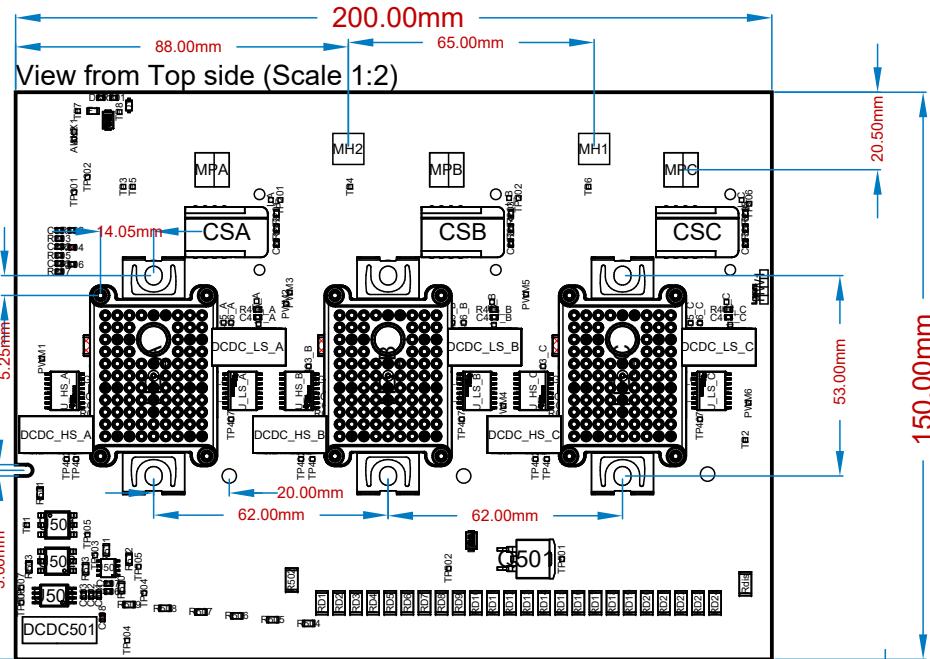




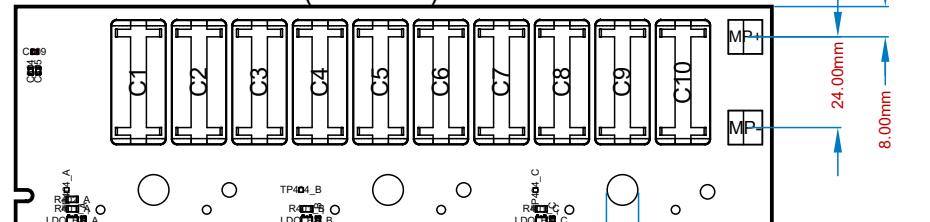




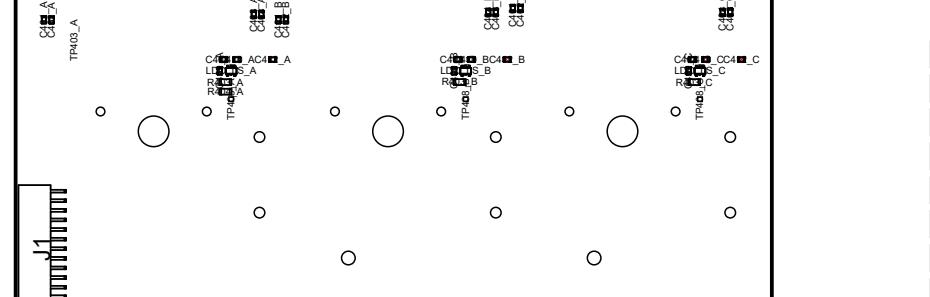
# Inverter Power



View from Top side (Scale 1:2)



View from Bottom side (Scale 1:2)



View from Back side (Scale 1:2)

## Bill Of Materials

Designator	Name	Quantity
C405_A, C405_B, C405_C, C406_A, C406_B, C406_C, C408_A, C408_B, C408_C, C409_A, C409_B, C409_C	10uF	12
C1, C2, C3, C4, C5, C6, C7, C8, C9, C10	10uF 850V	10
F1	0437001.WRA	1
DDCDC501	1779205141	1
J1	613026243121	1
D2	BZG05CSV1-E3-TR	1
R401_A, R401_B, R401_C, R403_A, R403_B, R403_C	CR1206-JW-563ELF	6
R402_A, R402_B, R402_C, R404_A, R404_B, R404_C	CR1206-JW-563ELF	6
R503	CRCW120610K0FKEA	1
R511	CRCW120630K0FKEA	1
HB_A, HB_B, HB_C	DF50HF12EYR1	3
HW1	LOGO CAPAS (4)	1
MP-, MP+, MPA, MPB, MPC	M4	5
M4	MBR0530	1
D1	Mounting Hole M4	2
MH1, MH2	RCV2512470KFKEG	24
RD1, RD2, RD3, RD4, RD5, RD6, RD7, RD8, RD9, RD10, RD11, RD12, RD13, RD14, RD15, RD16, RD17, RD18, RD19, RD20, RD21, RD22, RD23, RD24	CR0805-FX-1000ELF	3
R406_A, R406_B, R406_C	CR0805-JW-102ELF	1
R301	CR0805-JW-103ELF	12
R302, R305, R306, R405_A, R405_B, R405_C, RGS_HS_A, RGS_HS_B, RGS_HS_C, RGS_LS_A, RGS_LS_B, RGS_LS_C	CR1206FX-6802EAS	6
R504, R505, R506, R507, R508, R509	CR1206-FX-2201ELF	2
R501, R513	CRS1206-FX-4701ELF	2
R510, R512	LEM CKSR 50-NP	3
CSA, CSB, CSC	MJG16-series	6
DCDC_HS_A, DCDC_HS_B, DCDC_HS_C, DCDC_LS_A, DCDC_LS_B, DCDC_LS_C	LM311DR2G	1
U503	885012208058	1
C501	RG_OFF_HS_A, RG_OFF_HS_B, RG_OFF_HS_C, RG_OFF_LS_A, RG_OFF_LS_B, RG_OFF_LS_C, RG_ON_HS_A, RG_ON_HS_B, RG_ON_HS_C, RG_ON_LS_A, RG_ON_LS_B, RG_ON_LS_C	12
U504	CRG1206F100R	1
LDO_HS_A, LDO_HS_B, LDO_HS_C, LDO_LS_A, LDO_LS_B, LDO_LS_C	ISO224	1
U_HS_A, U_HS_B, U_HS_C, U_LS_A, U_LS_B, U_LS_C	TPS72301	6
Q501	UCC21710	6
R502, Rds	SIH150N60E-GE3	1
U501, U502	R2M-2512FTK	2
D501	4N35	2
D301	BZG05C6V2-E3-TR	1
C201, C202, C203, C402_A, C402_B, C402_C, C404_A, C404_B, C404_C, C411_A, C411_B, C411_C, C502, C504, C506	150080GS75000	1
C401_A, C401_B, C401_C, C403_A, C403_B, C403_C, C503, C505, C507	885012207098	15
	885012207103	9

Copper thickness in hole 25-50um, watch out for 1.10mm holes  
Chemical tin 1-15um

## Layer Stack Legend

Material	Layer	Thickness	Dielectric Material	Type	Gerber
	Top Overlay				Legend GTO
	Surface Material	0.01mm		Solder Resist	Solder Mask GTS
	CF-004	0.07mm		Signal GTL	Signal GTL
	Prepreg	0.10mm	PP-006	Dielectric	Dielectric
	Prepreg	0.10mm	PP-006	Dielectric	Dielectric
	Copper	0.07mm	FR-4	Signal G1	Signal G1
	Prepreg	0.90mm	PP-006	Dielectric	Dielectric
	Prepreg	0.10mm	PP-006	Dielectric	Dielectric
	Copper	0.07mm	PP-006	Signal G2	Signal G2
	Prepreg	0.10mm	PP-006	Dielectric	Dielectric
	CF-004	0.07mm	PP-006	Dielectric	Dielectric
	Surface Material	0.01mm		Solder Resist	Solder Mask GBS
	Bottom Overlay			Legend GBO	Legend GBO

Total thickness: 1.60mm